

**3LP02SP**

## Ultrahigh-Speed Switching Applications

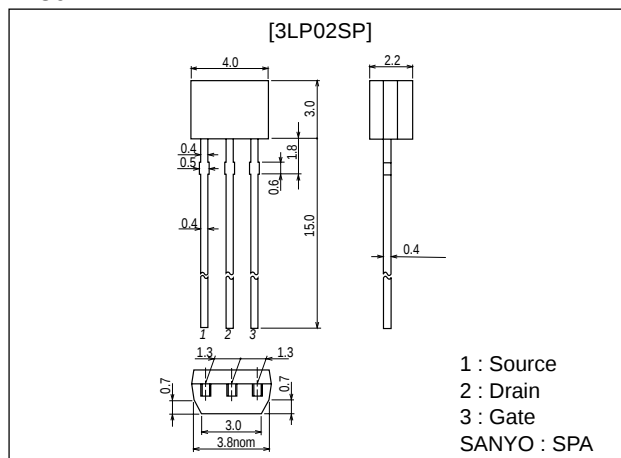
### Features

- Low ON-resistance.
- Ultrahigh-speed switching.
- 2.5V drive.

### Package Dimensions

unit:mm

2180



### Specifications

Absolute Maximum Ratings at  $T_a = 25^\circ\text{C}$ 

| Parameter                   | Symbol    | Conditions                                      | Ratings     | Unit             |
|-----------------------------|-----------|-------------------------------------------------|-------------|------------------|
| Drain-to-Source Voltage     | $V_{DSS}$ |                                                 | -30         | V                |
| Gate-to-Source Voltage      | $V_{GSS}$ |                                                 | $\pm 10$    | V                |
| Drain Current (DC)          | $I_D$     |                                                 | -0.2        | A                |
| Drain Current (pulse)       | $I_{DP}$  | $PW \leq 10\mu\text{s}$ , duty cycle $\leq 1\%$ | -0.8        | A                |
| Allowable Power Dissipation | $P_D$     |                                                 | 0.25        | W                |
| Channel Temperature         | $T_{ch}$  |                                                 | 150         | $^\circ\text{C}$ |
| Storage Temperature         | $T_{stg}$ |                                                 | -55 to +150 | $^\circ\text{C}$ |

Electrical Characteristics at  $T_a = 25^\circ\text{C}$ 

| Parameter                                  | Symbol        | Conditions                                       | Ratings |     |          | Unit          |
|--------------------------------------------|---------------|--------------------------------------------------|---------|-----|----------|---------------|
|                                            |               |                                                  | min     | typ | max      |               |
| Drain-to-Source Breakdown Voltage          | $V_{(BR)DSS}$ | $I_D = -1\text{mA}$ , $V_{GS} = 0$               | -30     |     |          | V             |
| Zero-Gate Voltage Drain Current            | $I_{DSS}$     | $V_{DS} = -30\text{V}$ , $V_{GS} = 0$            |         |     | -10      | $\mu\text{A}$ |
| Gate-to-Source Leakage Current             | $I_{GSS}$     | $V_{GS} = \pm 8\text{V}$ , $V_{DS} = 0$          |         |     | $\pm 10$ | $\mu\text{A}$ |
| Cutoff Voltage                             | $V_{GS(off)}$ | $V_{DS} = -10\text{V}$ , $I_D = -100\mu\text{A}$ | -0.4    |     | -1.4     | V             |
| Forward Transfer Admittance                | $ y_{fs} $    | $V_{DS} = -10\text{V}$ , $I_D = -100\text{mA}$   | 0.21    | 0.3 |          | S             |
| Static Drain-to-Source On-State Resistance | $R_{DS(on)1}$ | $I_D = -100\text{mA}$ , $V_{GS} = -4\text{V}$    |         | 2.4 | 3.1      | $\Omega$      |
|                                            | $R_{DS(on)2}$ | $I_D = -50\text{mA}$ , $V_{GS} = -2.5\text{V}$   |         | 3.5 | 4.9      | $\Omega$      |
|                                            | $R_{DS(on)3}$ | $I_D = -10\text{mA}$ , $V_{GS} = -1.5\text{V}$   |         | 10  | 20       | $\Omega$      |

Marking : XD

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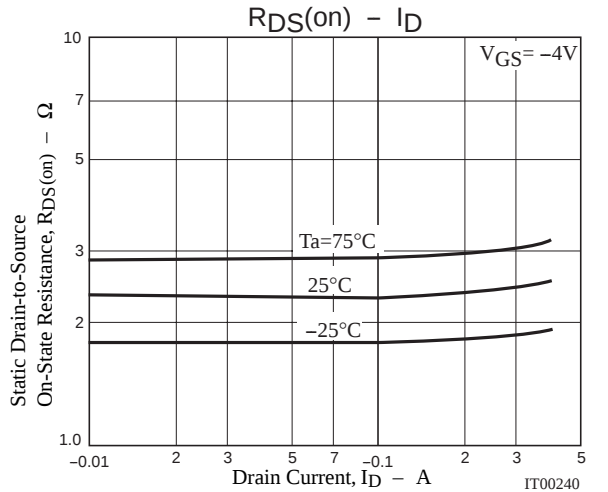
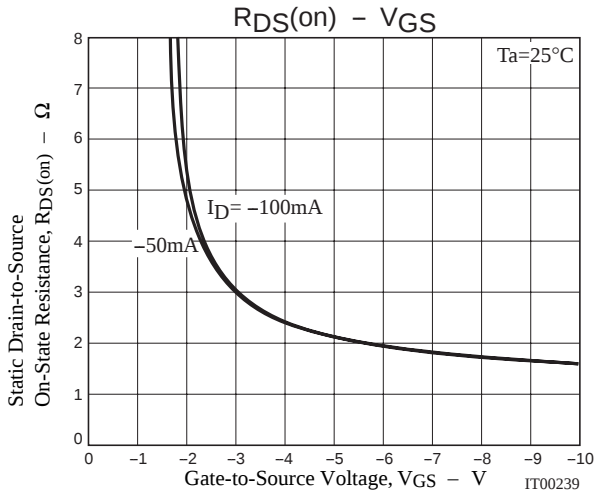
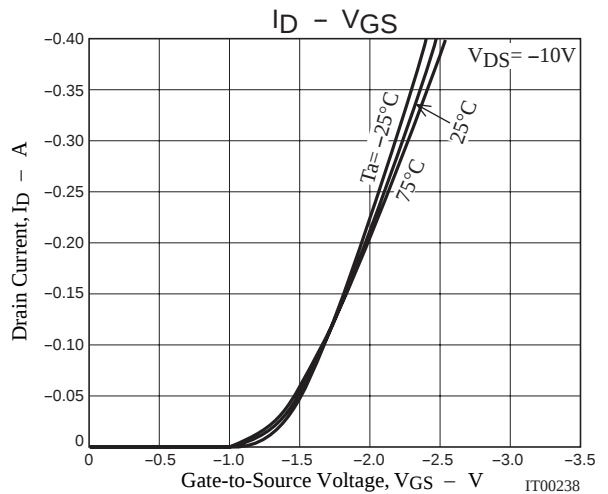
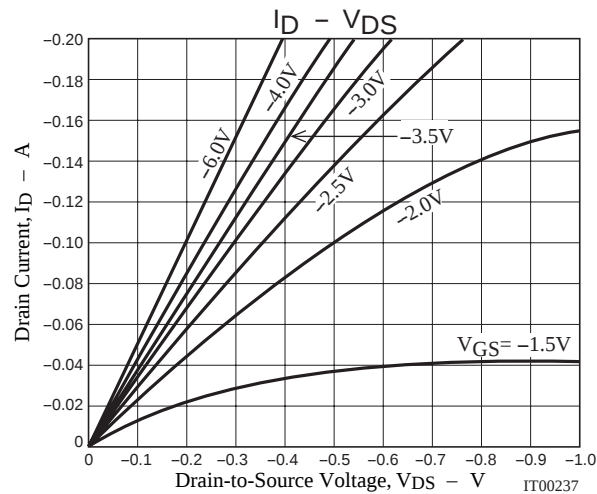
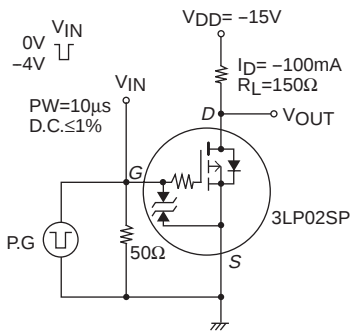
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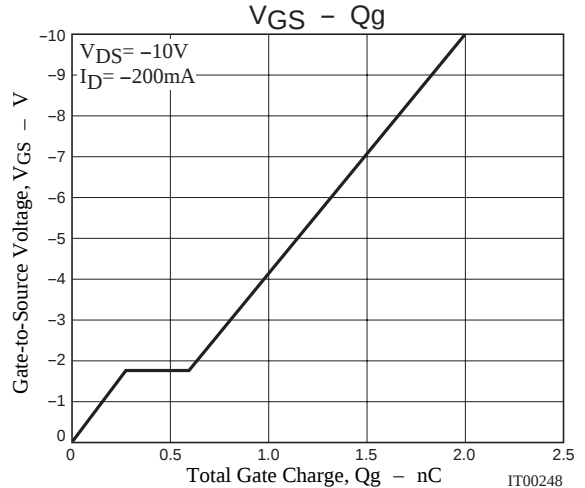
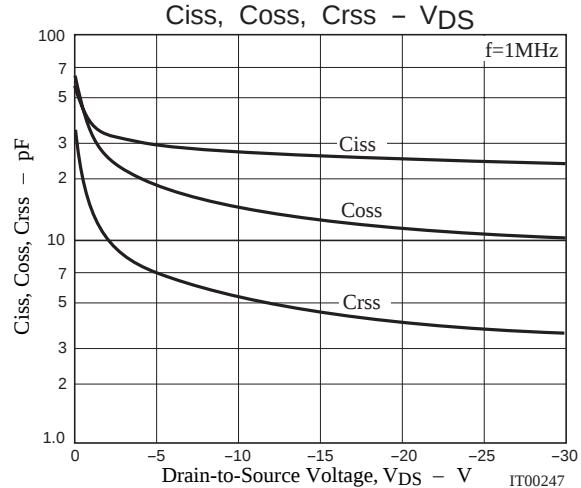
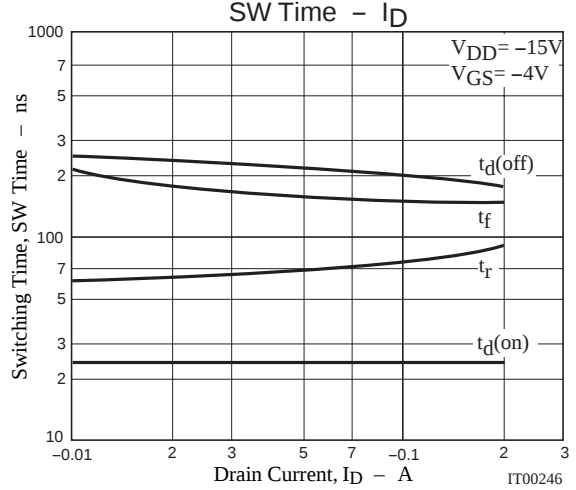
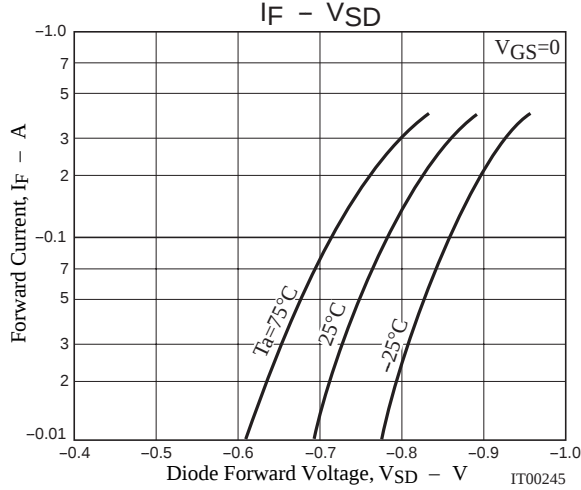
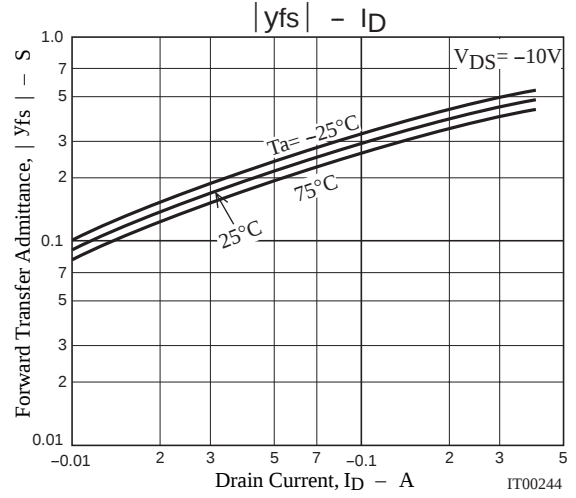
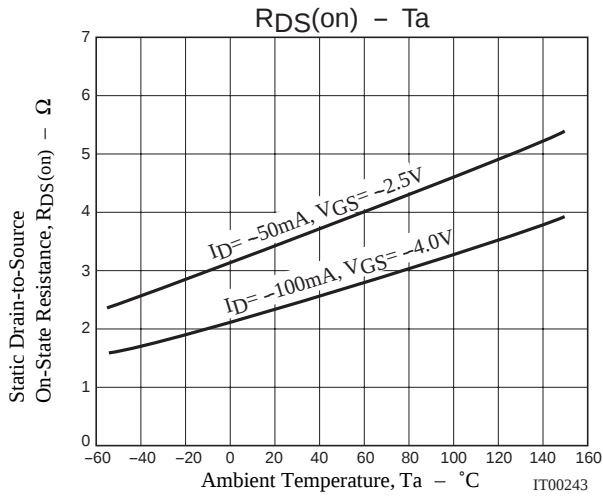
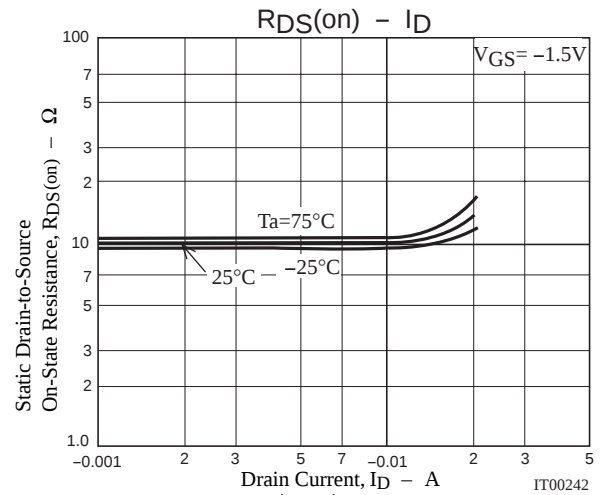
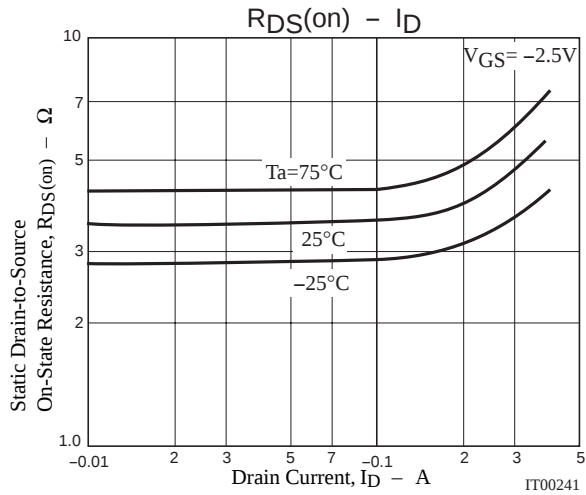
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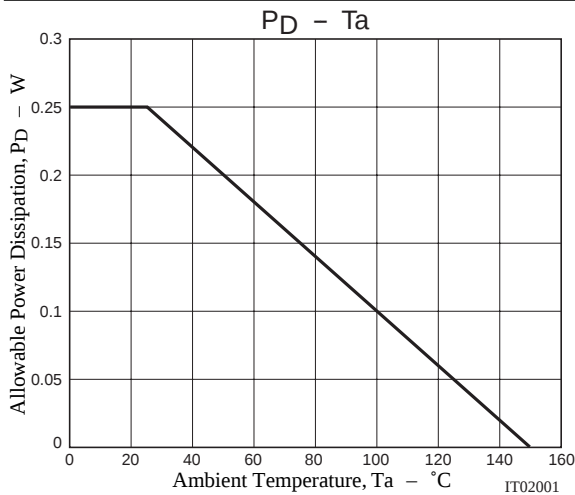
| Parameter                     | Symbol     | Conditions                             | Ratings |       |      | Unit |
|-------------------------------|------------|----------------------------------------|---------|-------|------|------|
|                               |            |                                        | min     | typ   | max  |      |
| Input Capacitance             | Ciss       | $V_{DS}=-10V, f=1MHz$                  |         | 28    |      | pF   |
| Output Capacitance            | Coss       | $V_{DS}=-10V, f=1MHz$                  |         | 15    |      | pF   |
| Reverse Transfer Capacitance  | Crss       | $V_{DS}=-10V, f=1MHz$                  |         | 5.2   |      | pF   |
| Turn-ON Delay Time            | $t_d(on)$  | See specified Test Circuit             |         | 24    |      | ns   |
| Rise Time                     | $t_r$      | See specified Test Circuit             |         | 75    |      | ns   |
| Turn-OFF Delay Time           | $t_d(off)$ | See specified Test Circuit             |         | 200   |      | ns   |
| Fall Time                     | $t_f$      | See specified Test Circuit             |         | 150   |      | ns   |
| Total Gate Charge             | Qg         | $V_{DS}=-10V, V_{GS}=-10V, I_D=-200mA$ |         | 2     |      | nC   |
| Gate-to-Source Charge         | Qgs        | $V_{DS}=-10V, V_{GS}=-10V, I_D=-200mA$ |         | 0.25  |      | nC   |
| Gate-to-Drain "Miller" Charge | Qgd        | $V_{DS}=-10V, V_{GS}=-10V, I_D=-200mA$ |         | 0.35  |      | nC   |
| Diode Forward Voltage         | $V_{SD}$   | $I_S=-200mA, V_{GS}=0$                 |         | -0.82 | -1.2 | V    |

Switching Time Test Circuit



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